

BSG0811NDATMA1

BSG0811NDATMA1 Information



For Reference Only

Part Number BSG0811NDATMA1

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 25V 19A/41A 8TISON

Package 8-PowerTDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BSG0811NDATMA1 Specifications

	Report errors?
Supplier Device Package	PG-TISON-8
Package / Case	8-PowerTDFN
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 150°C (TJ)
Power - Max	2.5W
Input Capacitance (Ciss) (Max) @ Vds	1100pF @ 12V
Gate Charge (Qg) (Max) @ Vgs	8.4nC @ 4.5V
Vgs(th) (Max) @ Id	2V @ 250μA
Rds On (Max) @ Id, Vgs	3 mOhm @ 20A, 10V
Current - Continuous Drain (Id) @ 25°C	19A, 41A
Drain to Source Voltage (Vdss)	25V
FET Feature	Logic Level Gate, 4.5V Drive
FET Type	2 N-Channel (Dual) Asymmetrical
Series	OptiMOS?
Package	8-PowerTDFN
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BSG0811NDATMA1 Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BSG0811NDATMA1 Payment Methods



















BSG0811NDATMA1 Shipping Methods













If you have any question about BSG0811NDATMA1, please do not hesitate to contact us!

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